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Kind regards,

Team Nexperia



# PESD12VV1BL

Very low capacitance bidirectional ESD protection diode

14 October 2016

Product data sheet

## 1. General description

Very low capacitance bidirectional ElectroStatic Discharge (ESD) protection diode designed to protect one signal line from the damage caused by ESD and other transients. The device is housed in a leadless ultra small DFN1006-2 (SOD882) Surface-Mounted Device (SMD) plastic package.

## 2. Features and benefits

- Bidirectional ESD protection of one line
- Low diode capacitance  $C_d = 17 \text{ pF}$
- Rated peak pulse power:  $P_{PPM} = 290 \text{ W}$
- Ultra low leakage current  $I_{RM} < 1 \text{ nA}$
- ESD protection up to 30 kV
- IEC 61000-4-2; level 4 (ESD)
- IEC 61000-4-5 (surge);  $I_{PPM} = 7.8 \text{ A}$
- AEC-Q101 qualified

## 3. Applications

- Computers and peripherals
- Audio and video equipment
- Cellular handsets and accessories
- Portable electronics
- Communication systems

## 4. Quick reference data

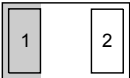
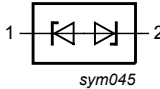
Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{RWM}$	reverse standoff voltage	$T_{amb} = 25 \text{ }^{\circ}\text{C}$	-	-	12	V
$C_d$	diode capacitance	$f = 1 \text{ MHz}; V_R = 0 \text{ V}; T_{amb} = 25 \text{ }^{\circ}\text{C}$	-	17	25	pF



## 5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode	 <p>Transparent top view</p> <p><b>DFN1006-2 (SOD882)</b></p>	 <p>sym045</p>
2	K	cathode		

## 6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PESD12VV1BL	DFN1006-2	DFN1006-2: leadless ultra small plastic package; 2 terminals	SOD882

## 7. Marking

Table 4. Marking codes

Type number	Marking code
PESD12VV1BL	MW

## 8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
$P_{PPM}$	rated peak pulse power		[1]	-	290	W
$I_{PPM}$	rated peak pulse current	$t_p = 8/20 \mu s$	[1]	-	7.8	A
$T_j$	junction temperature			-	150	°C
$T_{amb}$	ambient temperature			-55	150	°C
$T_{stg}$	storage temperature			-65	150	°C
<b>ESD maximum ratings</b>						
$V_{ESD}$	electrostatic discharge voltage	IEC 61000-4-2; contact discharge	[2]	-	30	kV
		machine model		-	400	V
		human body model (MIL-STD-883)		-	10	kV

[1] Device stressed with non-repetitive current pulses (8/20  $\mu s$  exponential decay waveform according to IEC 61000-4-5 and IEC 61643-321).

[2] Device stressed with ten non-repetitive ESD pulses.

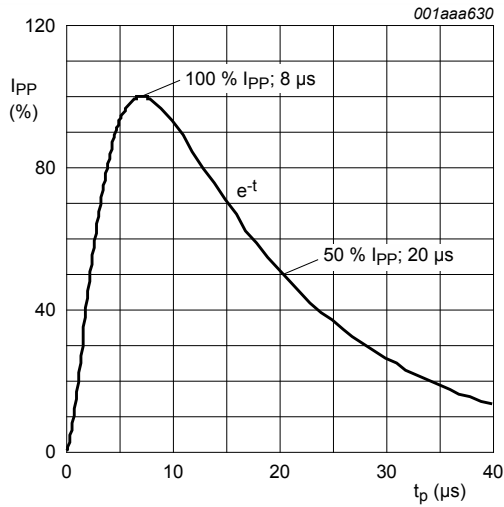


Fig. 1. 8/20  $\mu$ s pulse waveform according to IEC 61000-4-5 and IEC 61643-321

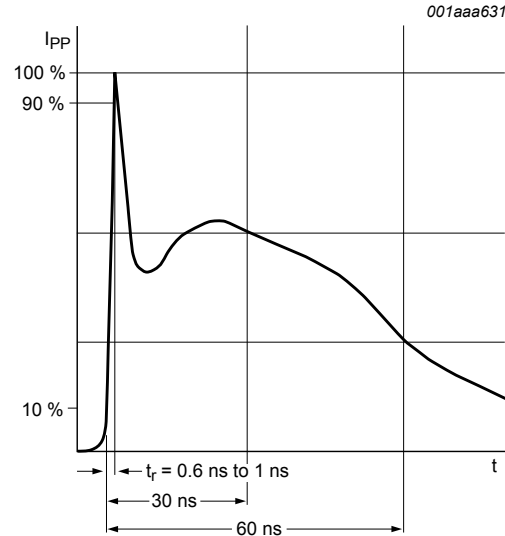


Fig. 2. ESD pulse waveform according to IEC 61000-4-2

## 9. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{RWM}$	reverse standoff voltage	$T_{amb} = 25\text{ }^{\circ}\text{C}$	-	-	12	V
$V_{BR}$	breakdown voltage	$I_R = 5\text{ mA}$ ; $T_{amb} = 25\text{ }^{\circ}\text{C}$	14.6	15.7	16.8	V
$I_{RM}$	reverse leakage current	$V_{RWM} = 12\text{ V}$ ; $T_{amb} = 25\text{ }^{\circ}\text{C}$	-	1	10	nA
$C_d$	diode capacitance	$f = 1\text{ MHz}$ ; $V_R = 0\text{ V}$ ; $T_{amb} = 25\text{ }^{\circ}\text{C}$	-	17	25	pF
$V_{CL}$	clamping voltage	$I_{PP} = 1\text{ A}$ ; $T_{amb} = 25\text{ }^{\circ}\text{C}$	[1]	-	22	V
		$I_{PPM} = 7.8\text{ A}$ ; $T_{amb} = 25\text{ }^{\circ}\text{C}$	[1]	-	38	V
$R_{dyn}$	dynamic resistance	$I_R = 10\text{ A}$ ; $T_{amb} = 25\text{ }^{\circ}\text{C}$	[2]	0.7	-	$\Omega$

[1] Device stressed with 8/20  $\mu$ s exponential decay waveform according to IEC 61000-4-5 and IEC 61643-321.

[2] Non-repetitive current pulse, Transmission Line Pulse (TLP)  $t_p = 100\text{ ns}$ ; square pulse; ANSI / ESD STM5.5.1-2008.

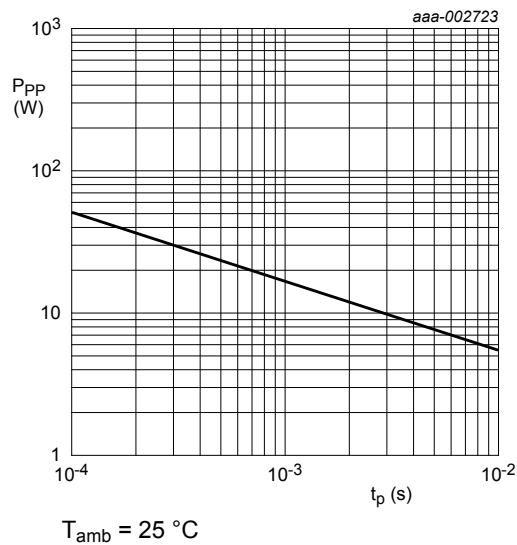


Fig. 3. Rated peak pulse power as a function of square pulse duration; maximum values

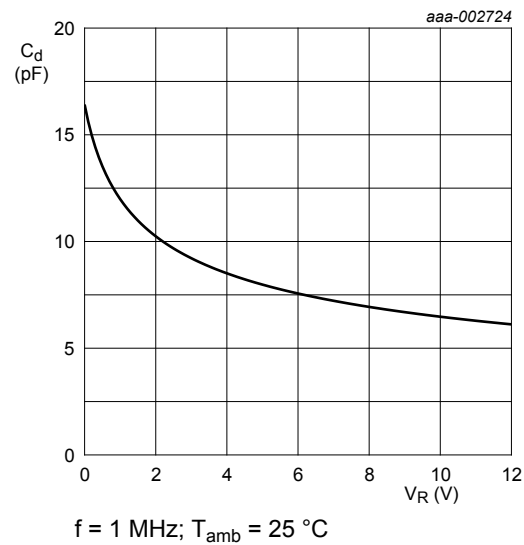


Fig. 4. Diode capacitance as a function of reverse voltage; typical values

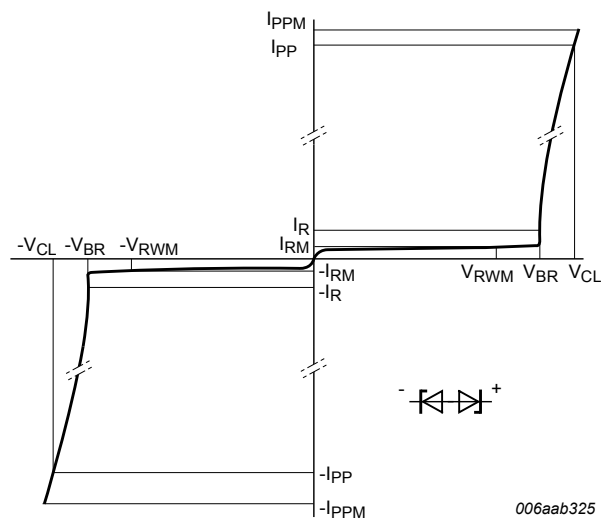


Fig. 5. V-I characteristics for a bidirectional ESD protection diode

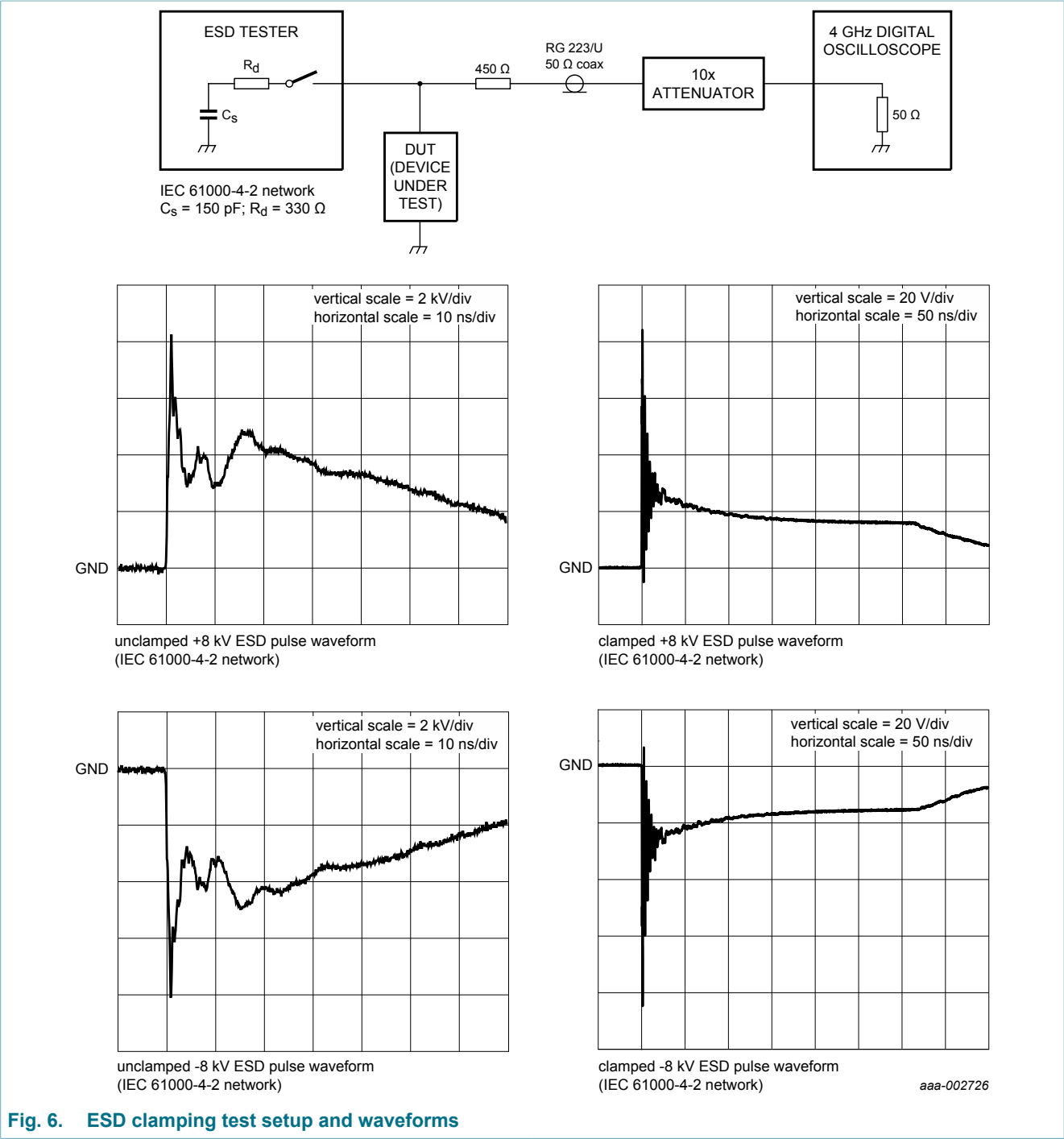
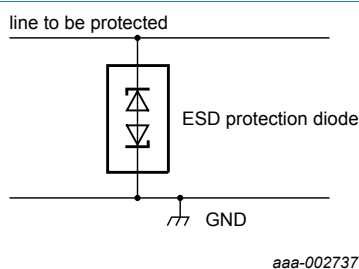


Fig. 6. ESD clamping test setup and waveforms

## 10. Application information

The device is designed for the protection of one bidirectional data line from surge pulses and ESD damage. The device is suitable on lines where the signal polarities are both positive and negative with respect to ground.



**Fig. 7. Application diagram**

### Circuit board layout and protection device placement

Circuit board layout is critical for the suppression of ESD, Electrical Fast Transient (EFT) and surge transients. The following guidelines are recommended:

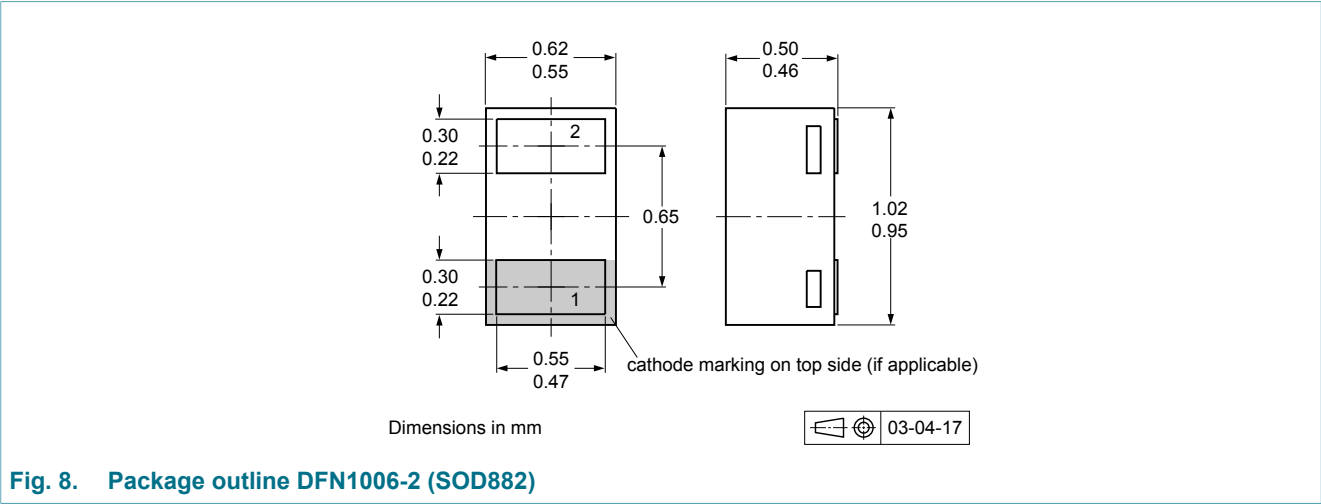
1. Place the device as close to the input terminal or connector as possible.
2. Minimize the path length between the device and the protected line.
3. Keep parallel signal paths to a minimum.
4. Avoid running protected conductors in parallel with unprotected conductors.
5. Minimize all Printed-Circuit Board (PCB) conductive loops including power and ground loops.
6. Minimize the length of the transient return path to ground.
7. Avoid using shared transient return paths to a common ground point.
8. Use ground planes whenever possible. For multilayer PCBs, use ground vias.

## 11. Test information

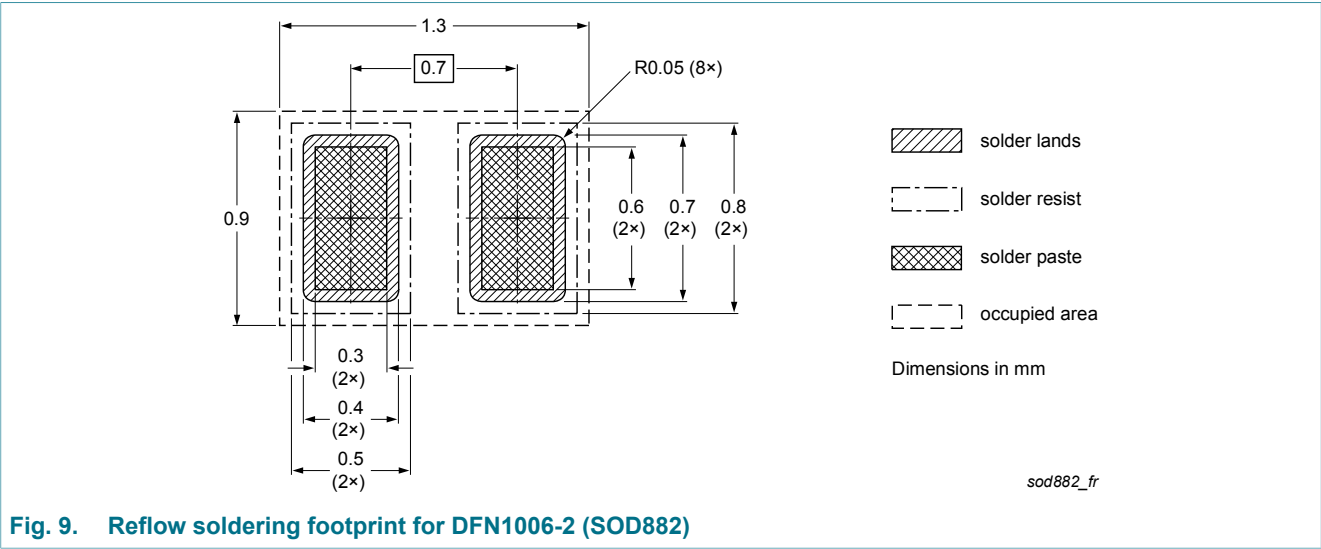
### Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

12. Package outline



13. Soldering





## 14. Revision history

Table 7. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PESD12VV1BL v.3	20161014	Product data sheet	-	PESD12VV1BL v.2
Modifications:	<ul style="list-style-type: none"><li>Deleted section "Packing information"</li></ul>			
PESD12VV1BL v.2	20130318	Product data sheet	-	PESD12VV1BL v.1
PESD12VV1BL v.1	20120403	Product data sheet	-	-

## 15. Legal information

### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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## 16. Contents

1. General description.....	1
2. Features and benefits.....	1
3. Applications.....	1
4. Quick reference data.....	1
5. Pinning information.....	2
6. Ordering information.....	2
7. Marking.....	2
8. Limiting values.....	2
9. Characteristics.....	3
10. Application information.....	6
11. Test information.....	6
12. Package outline.....	7
13. Soldering.....	7
14. Revision history.....	8
15. Legal information.....	9

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